

Zinc oxide nanorod p-n junction piezoelectric energy harvesters: mechanism, developments and applications

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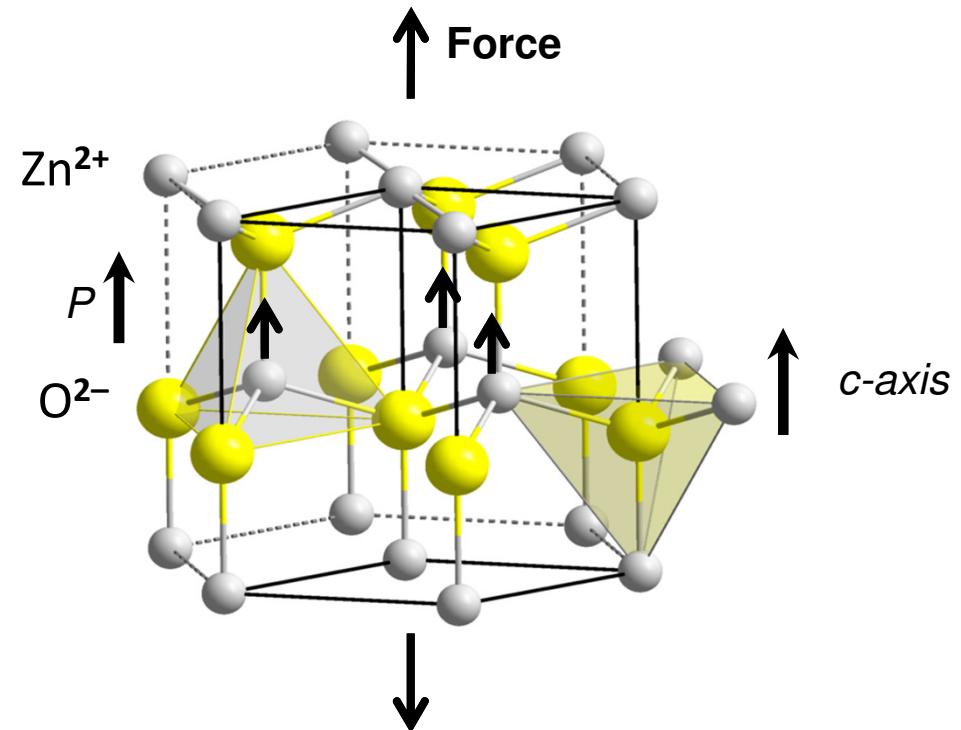
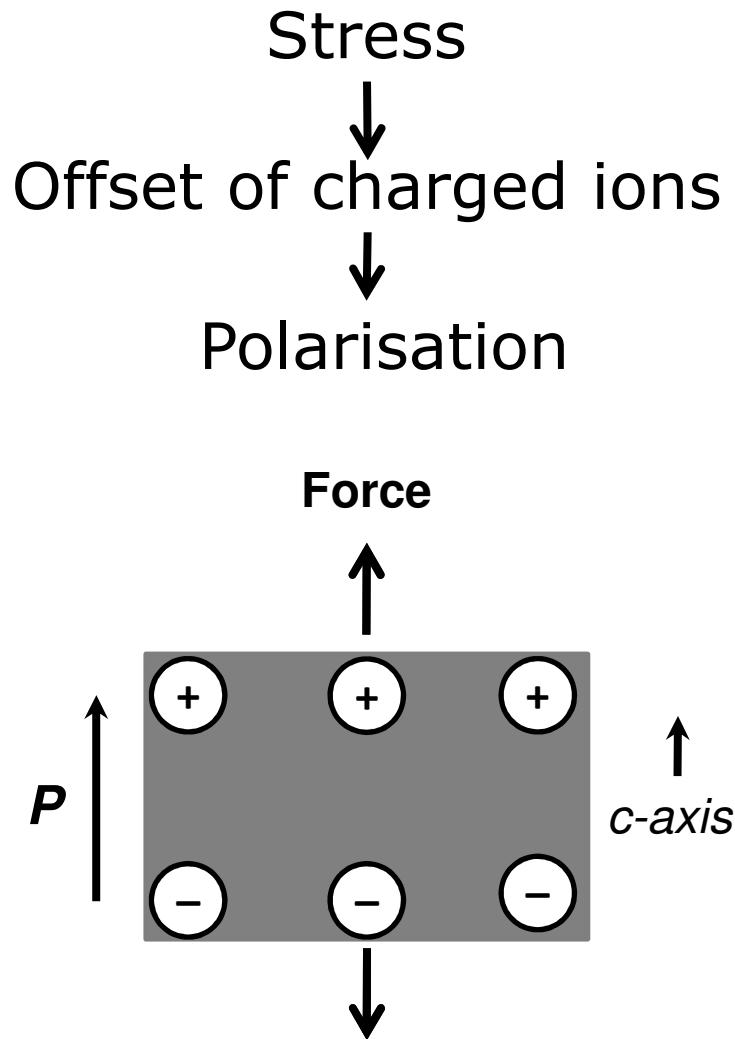
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Outline

- Background principles
- Synthesis Method
- ZnO nanorod morphology
- Screening, p-n junctions and passivation
- Proper characterisation
- Wireless sensor nodes
- Recent developments

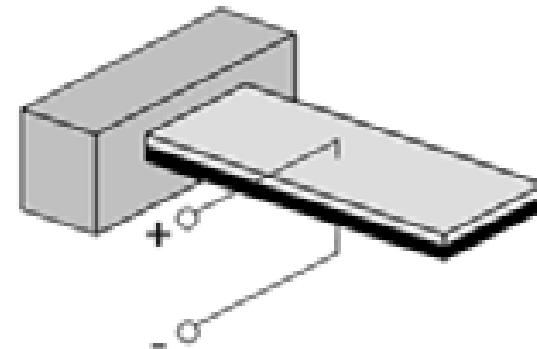
Piezoelectric effect



- Polarisation → potential difference if unscreened

Piezoelectric energy harvesting

- Basic design developed from piezoelectric sensors: cantilever vibrates and alternating charge harvested in external circuit
- Lead zirconate titanate (PZT) most common material used for energy harvestors



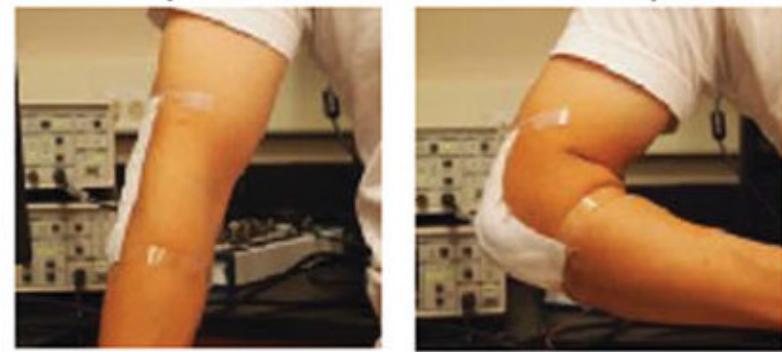
Anton and Sodano
Smart Materials and Structures
16, R1–R21 (2007).

Cook-Chennault, Thambi, and Sastry
Smart Materials and Structures
17, 43001 (2008).

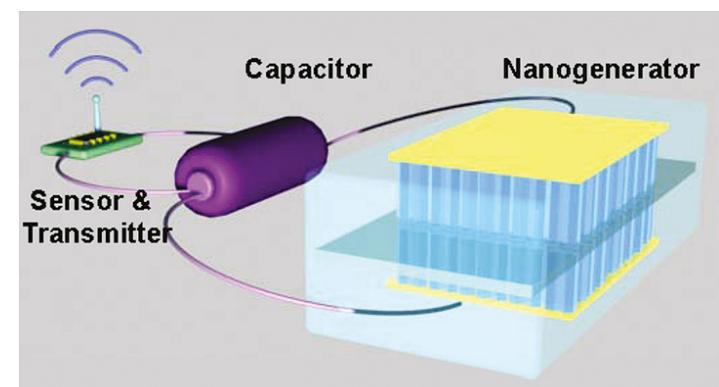
Beeby, Tudor, and White
Measurement Science and Technology
17, R175 (2006).

Piezoelectric energy harvesting

- Power microdevices or charge batteries
- On clothing, in remote locations, etc.
- Potential for self-powered systems



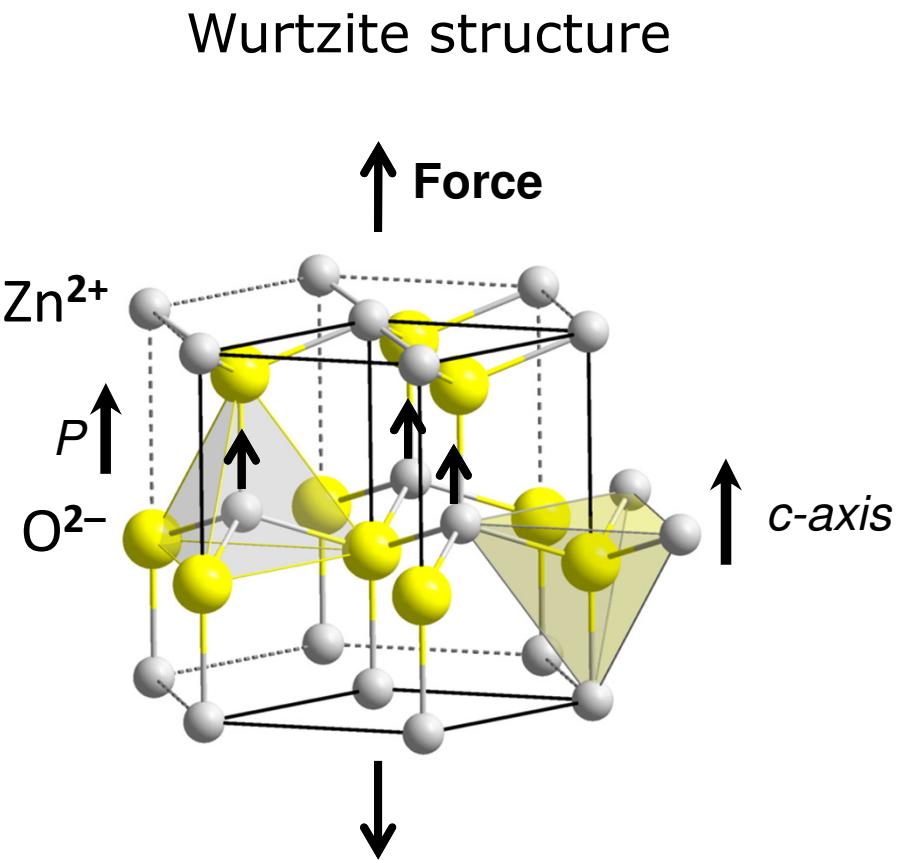
Lee *et al.* *Adv. Mater.* **24**, 1759–1764 (2012)



Hu *et al.* *Nano Lett.* **11**, 2572–2577 (2011)

Why ZnO nanorods?

- Lower d_{33} than many other piezoelectrics
ZnO: 5-12 pC/N,¹
PZT: 100-400 pC/N.²
- Easily produced nanostructures – solution synthesis
- Can coat almost any surface

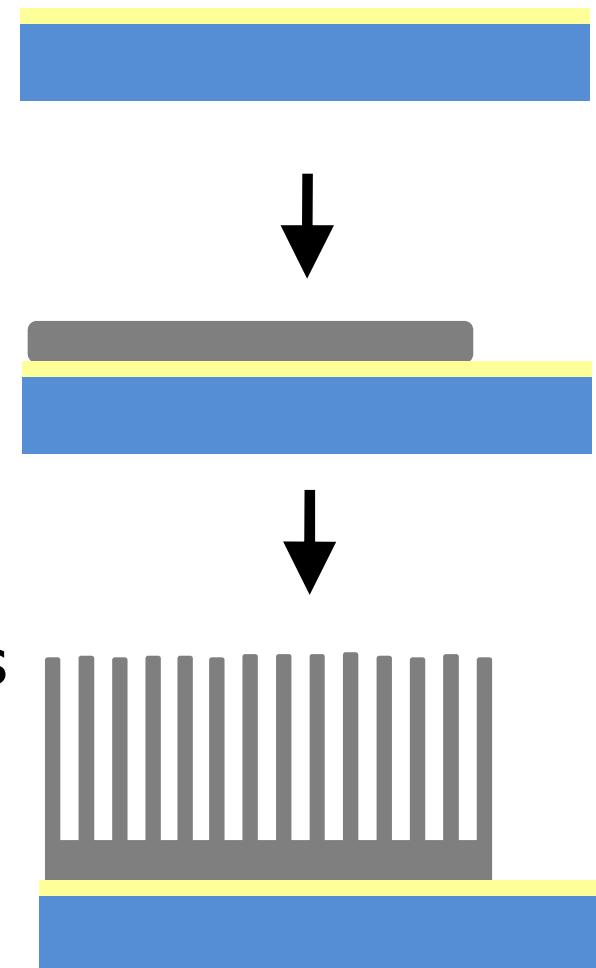


¹ Tokarev *et al.* Sov. Phys. Solid State **17** 629 (1975).

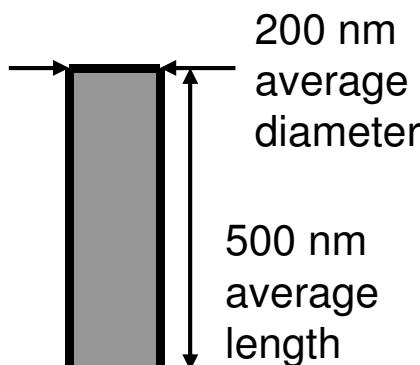
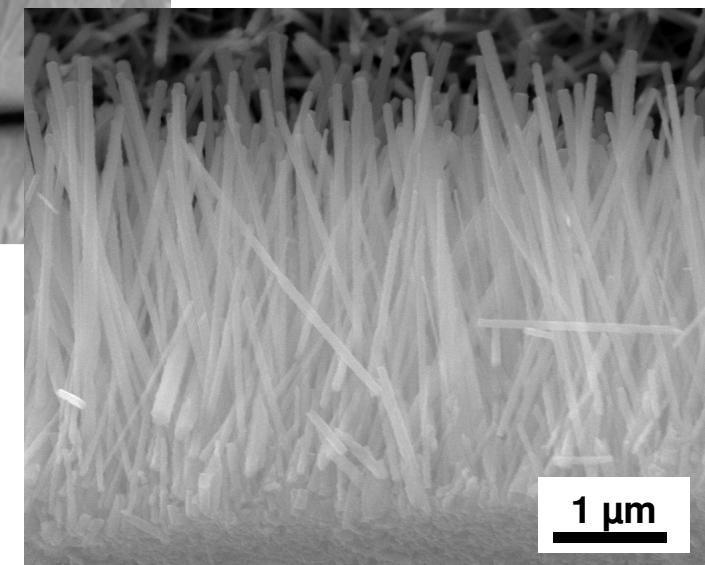
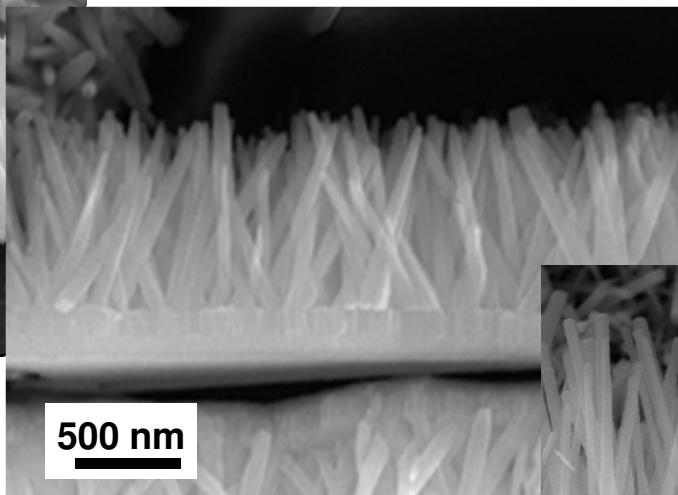
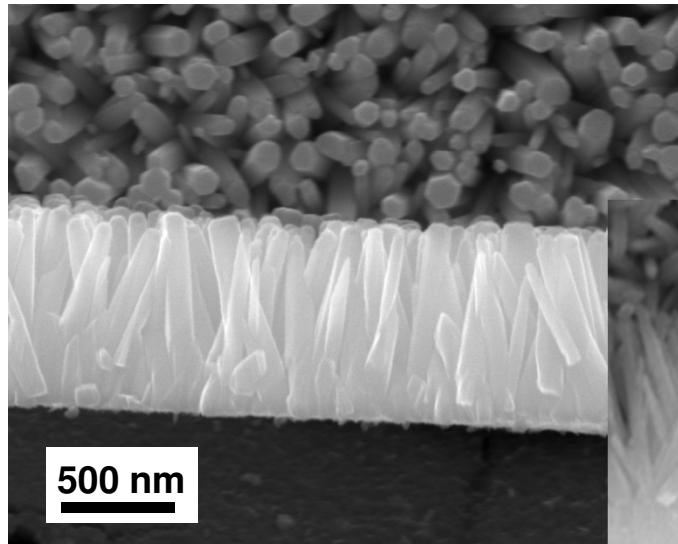
² Ledermann *et al.* Sens. Act. A **105**, 162 (2003).

ZnO nanorod synthesis

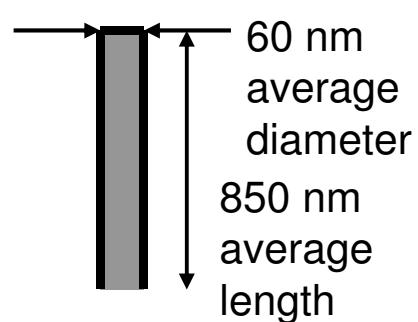
- Conductive substrates:
polyethylene terephthalate
(PET) coated with indium-tin
oxide (ITO)
- Sputtered ZnO seed layer
- ZnO nanorods grown in aqueous
chemical bath at 90 °C using
zinc nitrate and
hexamethylenetetramine (HMT)



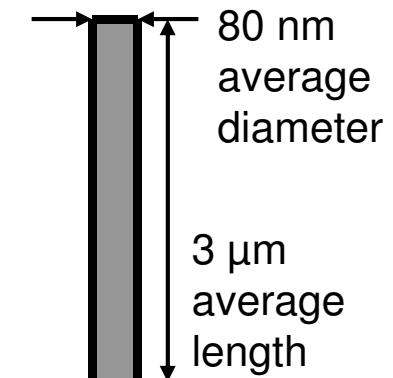
ZnO nanorods



200 nm
average
diameter
500 nm
average
length

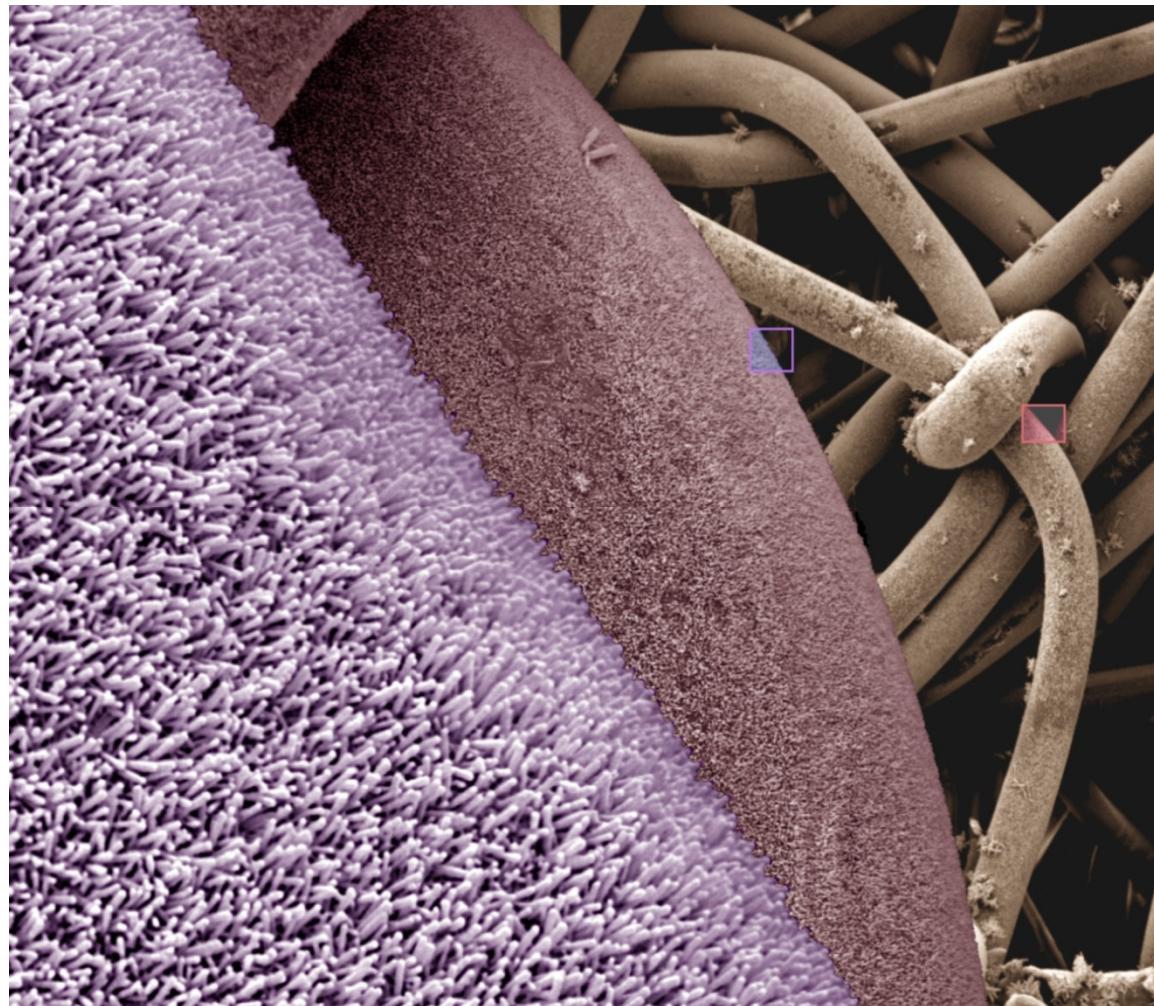


60 nm
average
diameter
850 nm
average
length



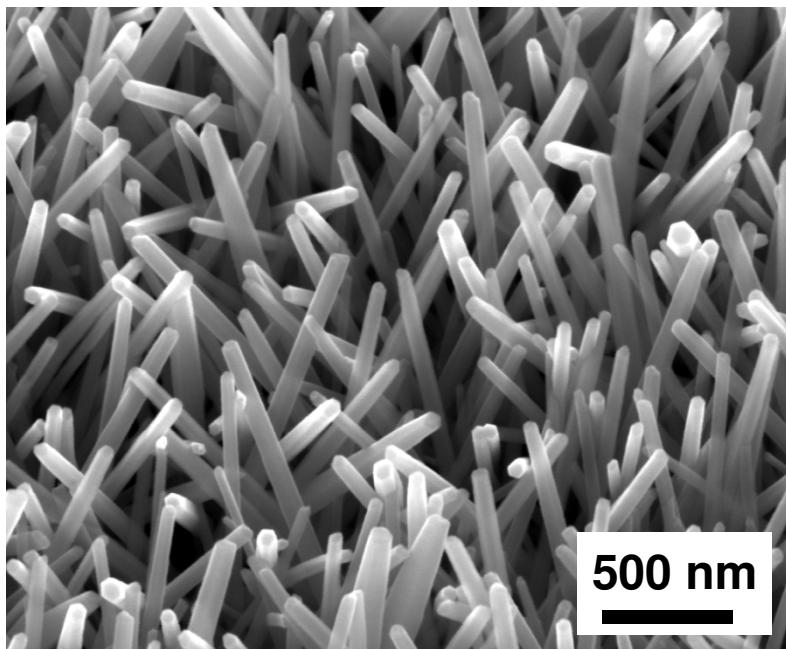
80 nm
average
diameter
3 μ m
average
length

ZnO nanorods

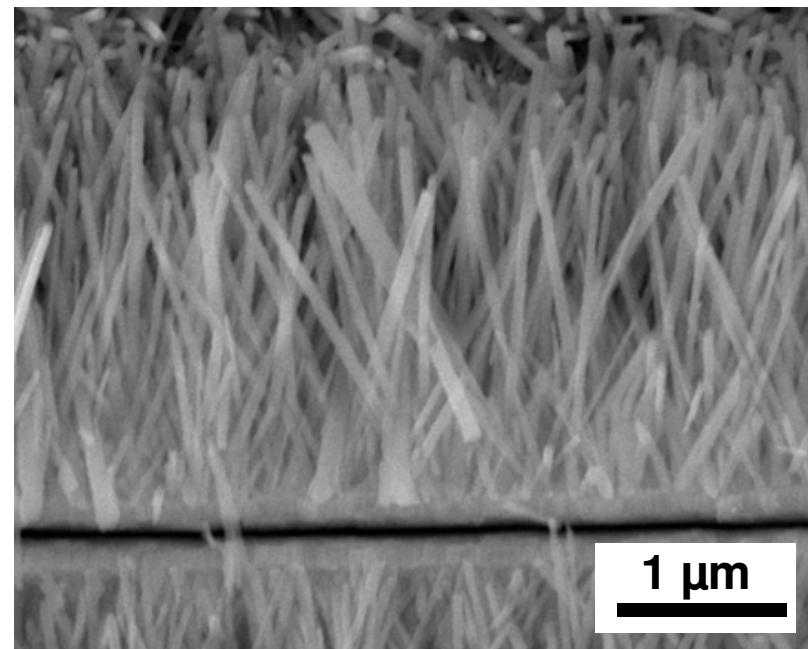


ZnO nanorods: energy harvestors

30° tilt



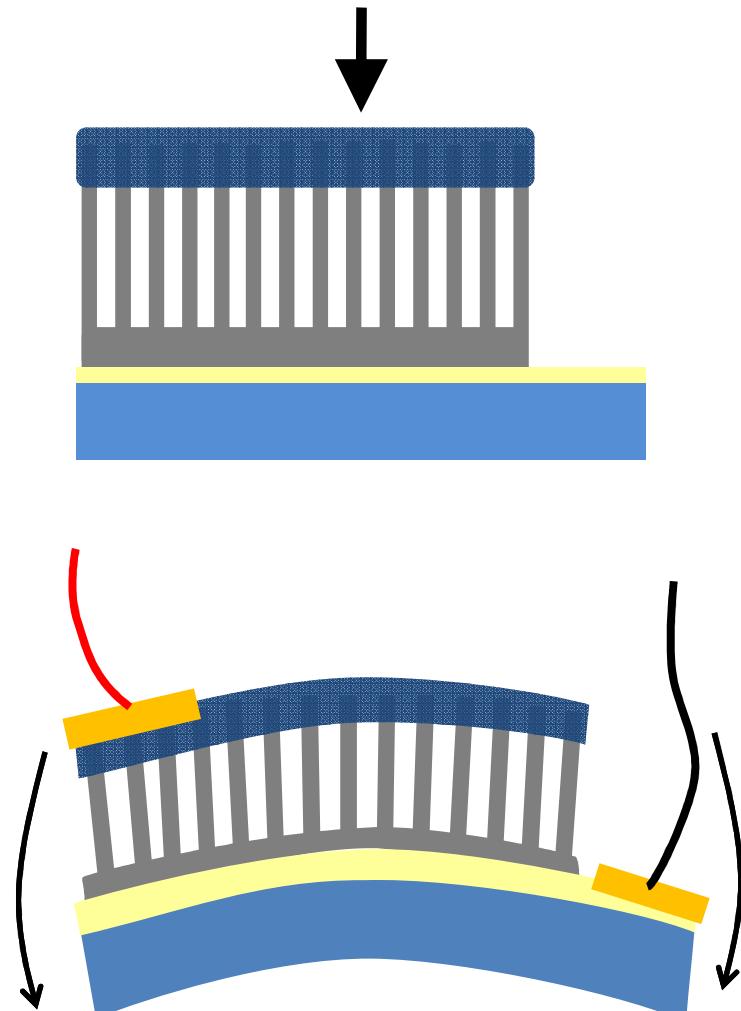
Cross-section



- Average diameter 75 nm
- Average length 2 μm
- Aspect ratio ~25:1

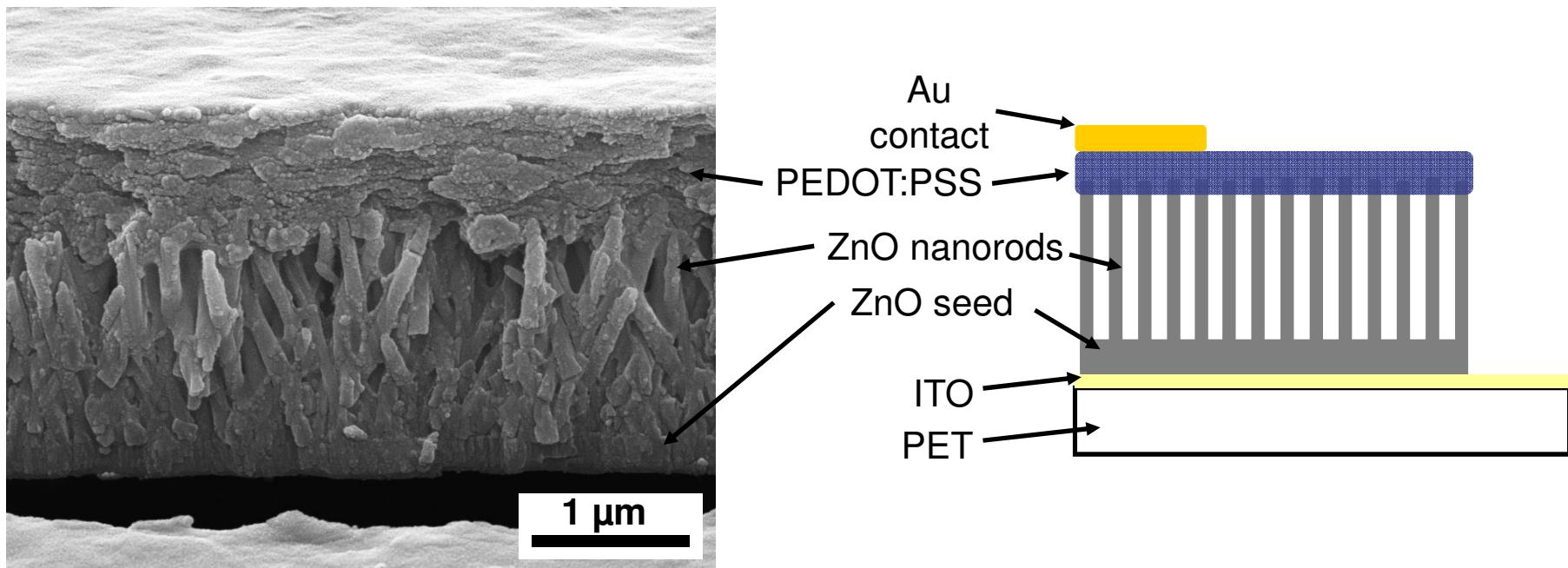
Device fabrication

- P-type layer added → diode
 - PEDOT:PSS spray-coated from aqueous suspension
- Electrodes added → flexible energy harvesting device

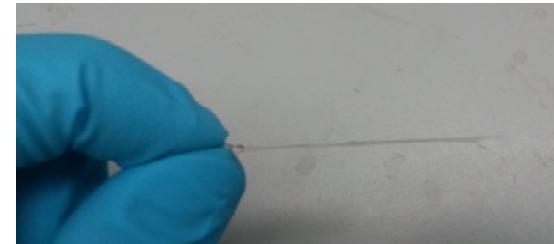
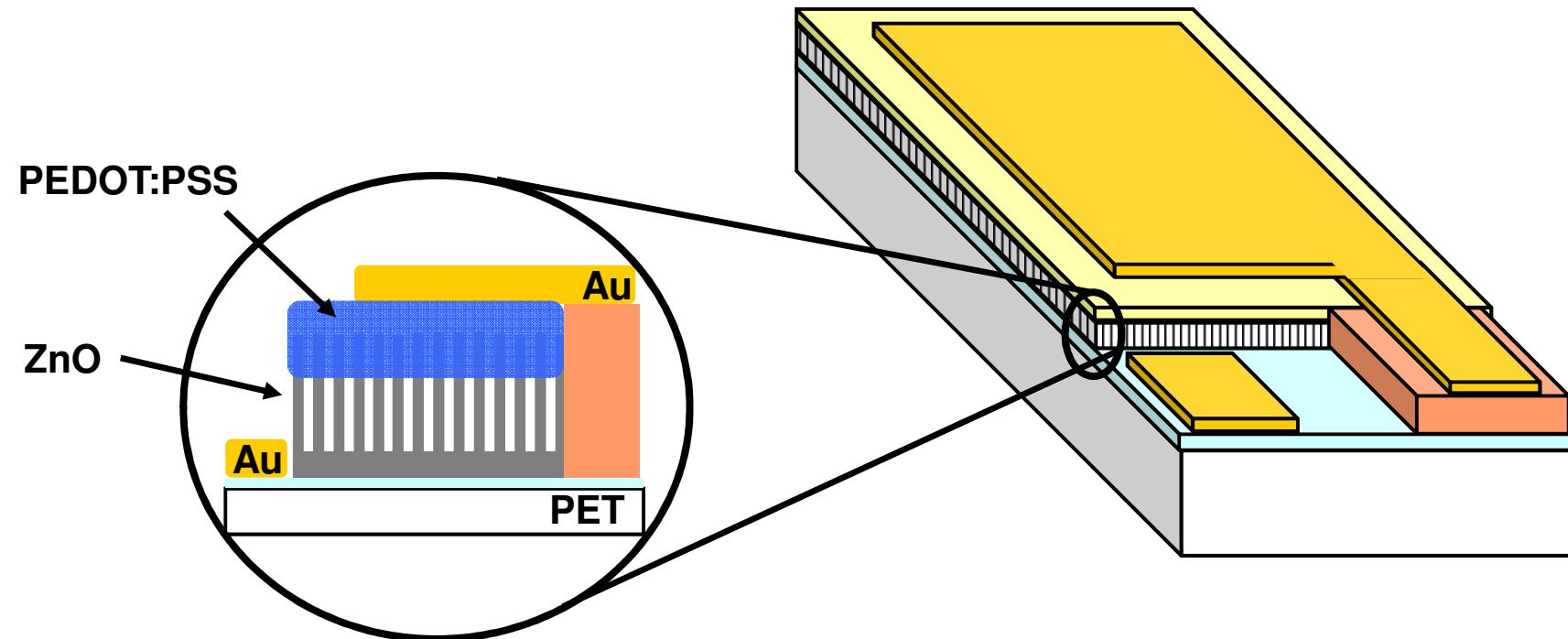


Device fabrication

- PEDOT:PSS spin-coated → p-n junction

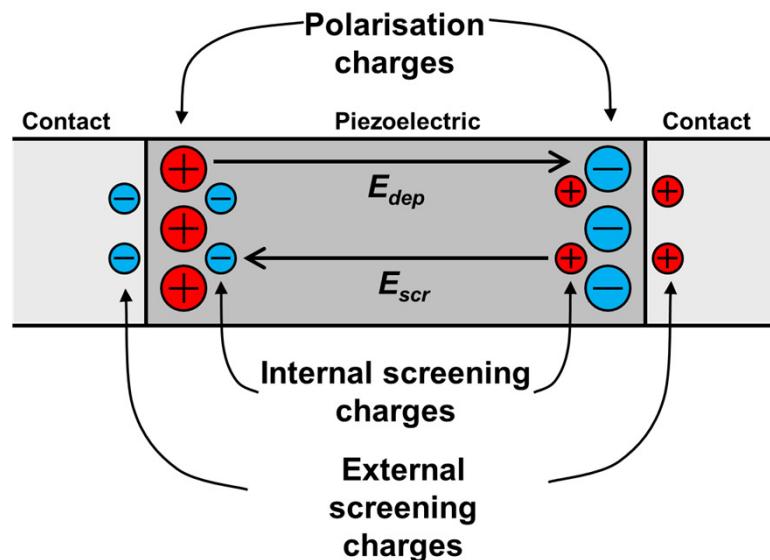


Device structure



PEDOT:PSS and screening

- Screening reduces measured potential difference
- Metal contacts and internal carriers screen rapidly
- Built-in bias at p-n junction reduces screening rate
- Slower screening from p-type → voltage measured



E_{dep} – depolarisation field

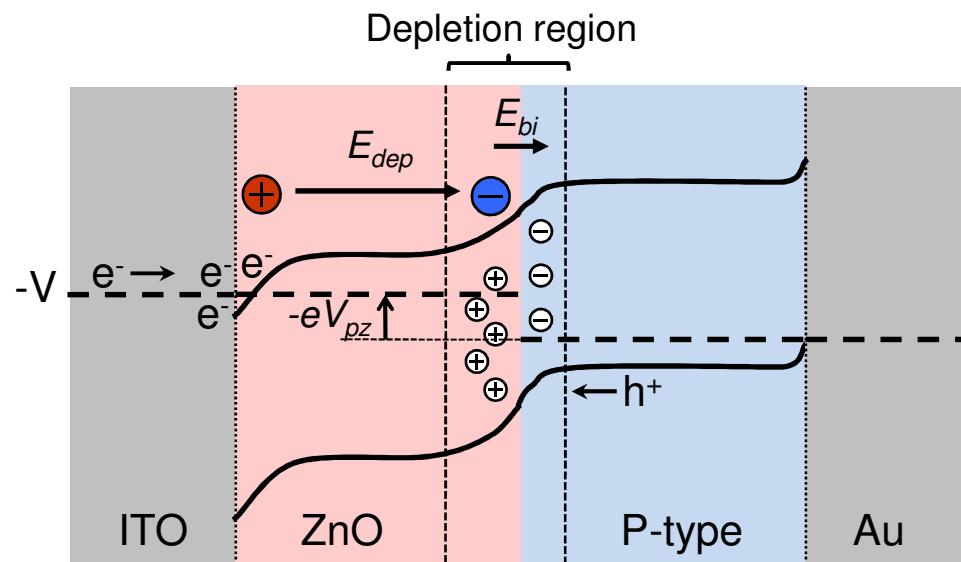
E_{scr} – screening field

$$V_{out} \propto E_{dep} - E_{scr}$$

Briscoe et al., *Adv. Energy Mater.* **2**, 1261–1268. (2012).
 doi: 10.1002/aenm.201200205

PEDOT:PSS and screening

- Screening reduces measured potential difference
- Metal contacts and internal carriers screen rapidly
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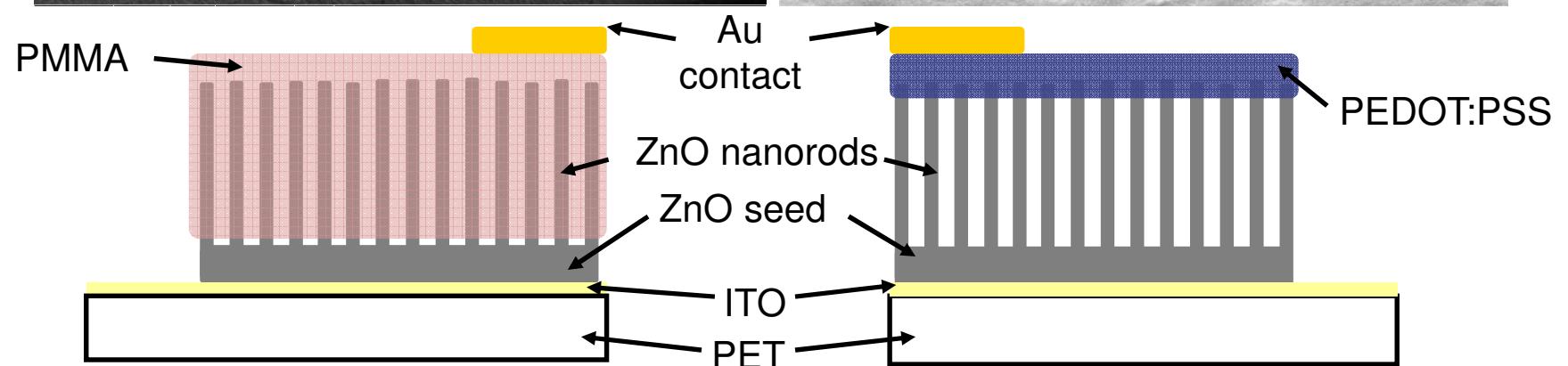
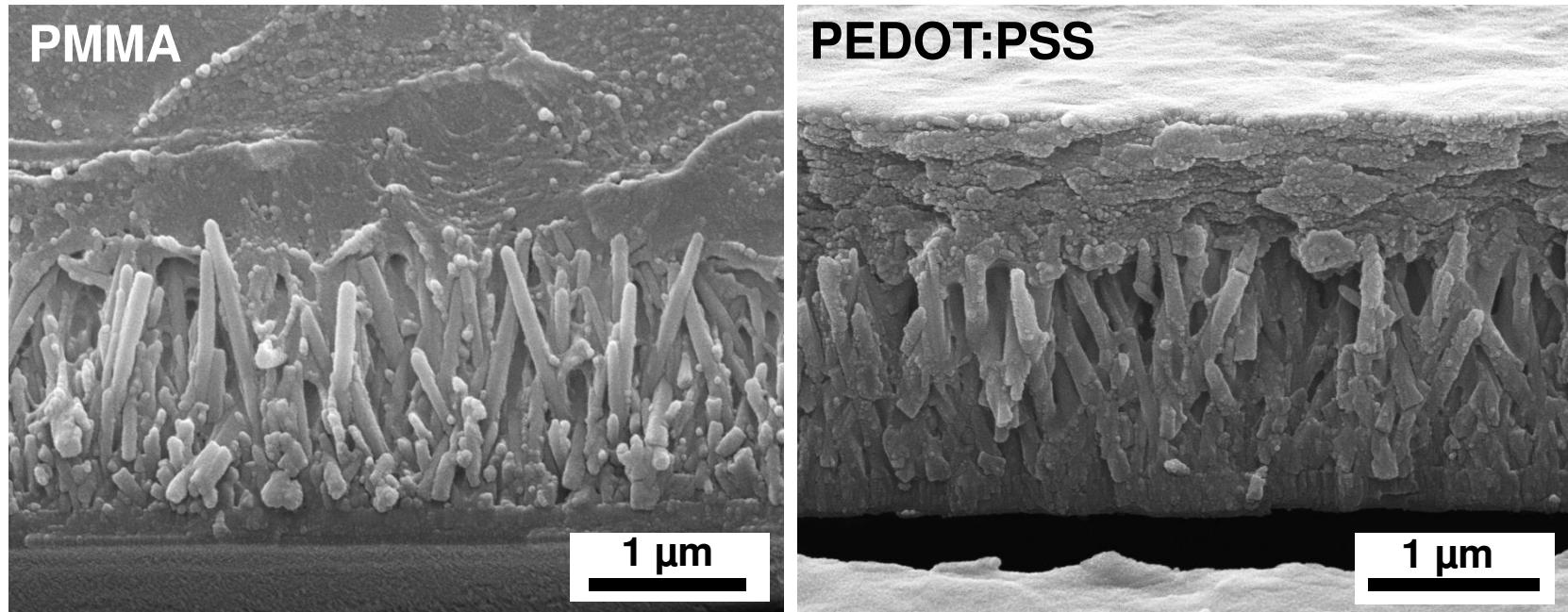
E_{dep} – depolarisation field

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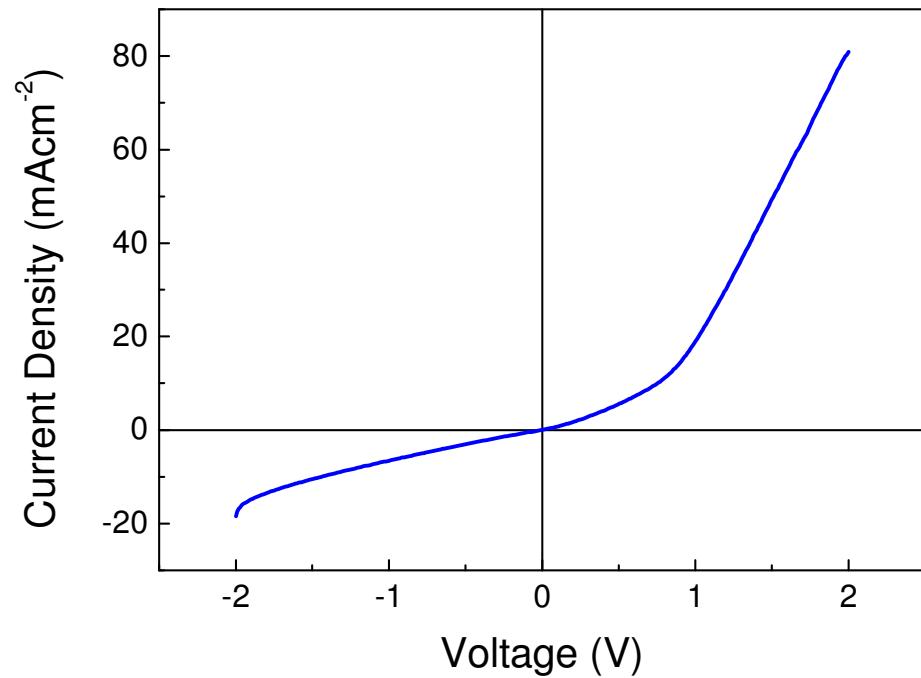
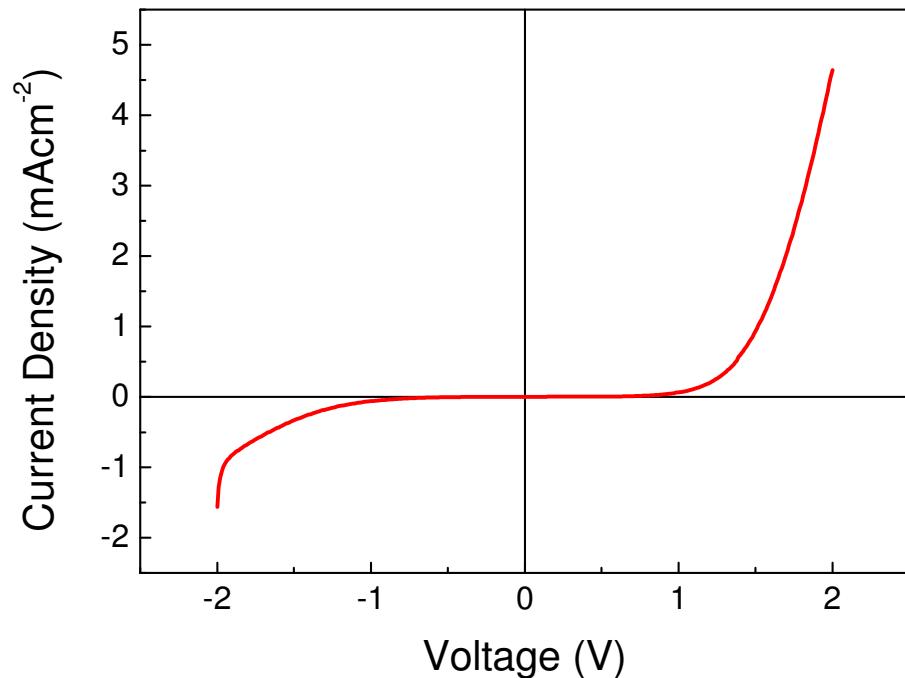
Briscoe et al., *Adv. Energy Mater.* **2**, 1261–1268. (2012).
doi: 10.1002/aenm.201200205

Device comparison

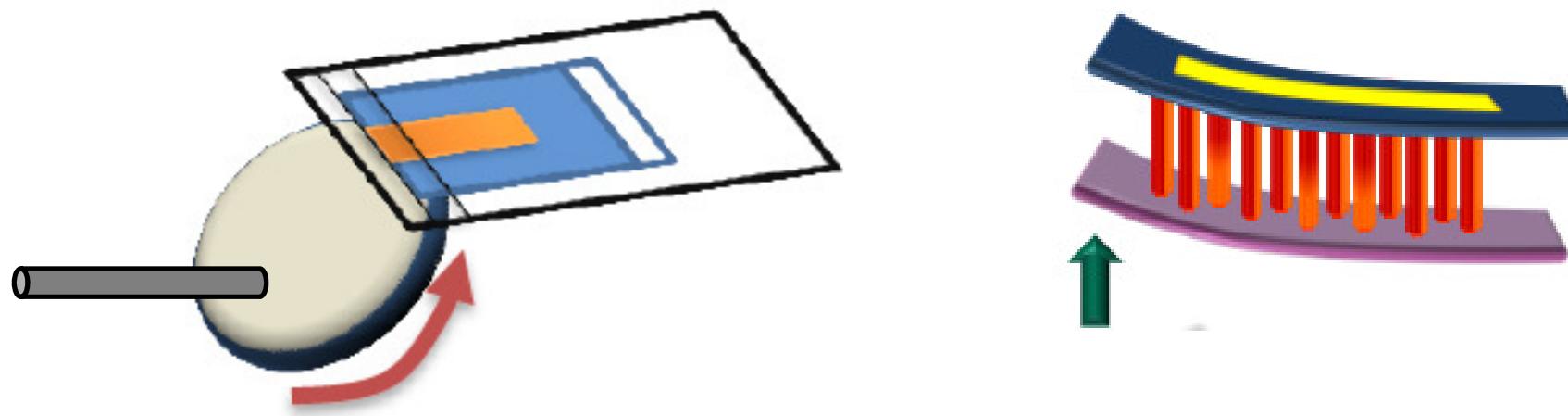


Current-voltage

- ZnO/PMMA
- High resistance with almost symmetrical breakdown
- PEDOT:PSS
- Diode characteristics with high leakage



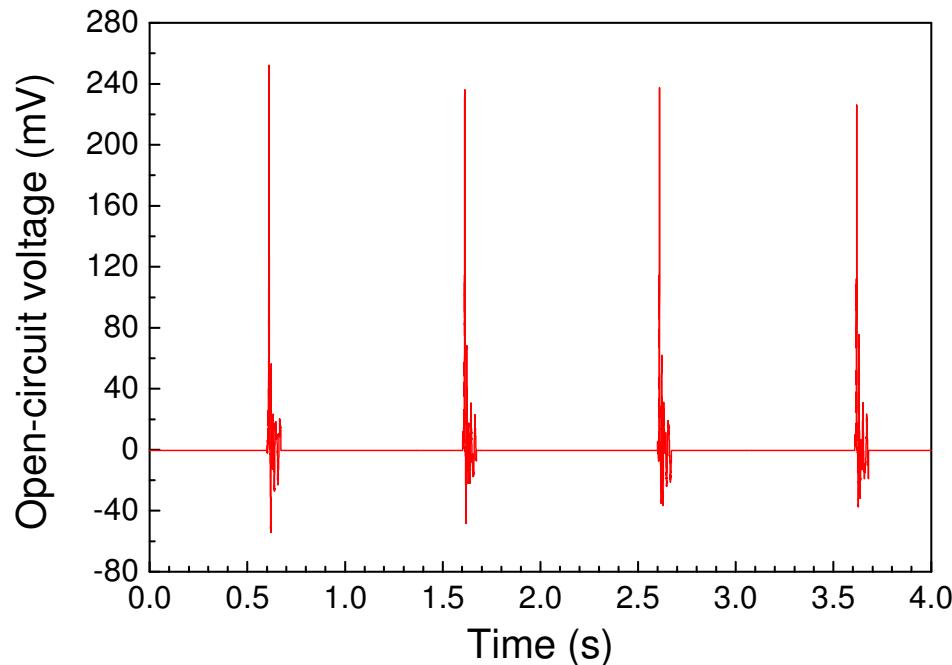
Controlled bending



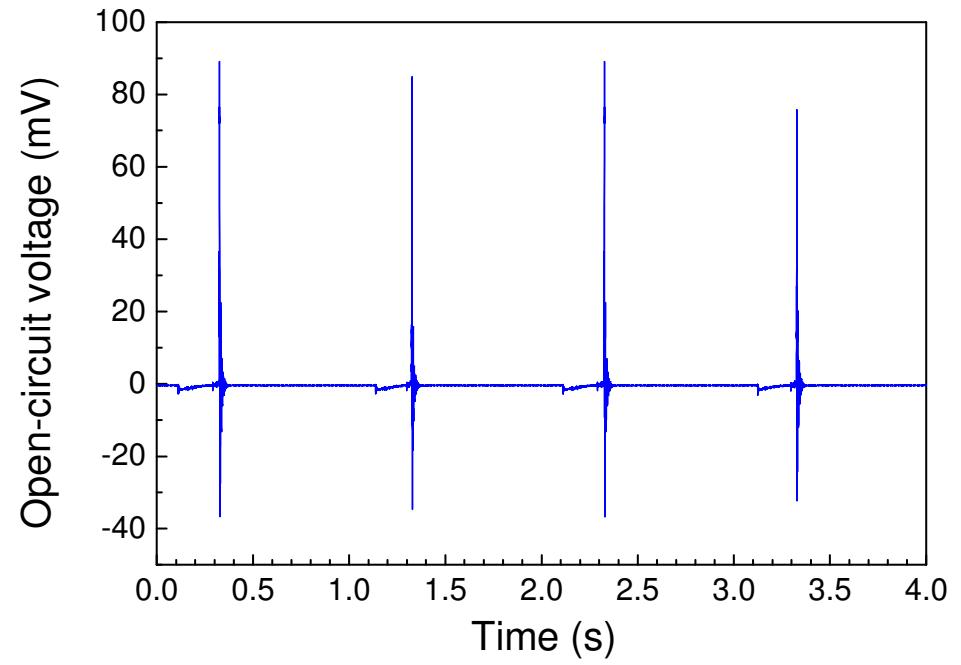
- Cam used to produce controllable deflection of flexible substrate
- Voltage or current peak measured as substrate drops from cam
- Avoids resonance effects of substrate

Controlled bending

PMMA



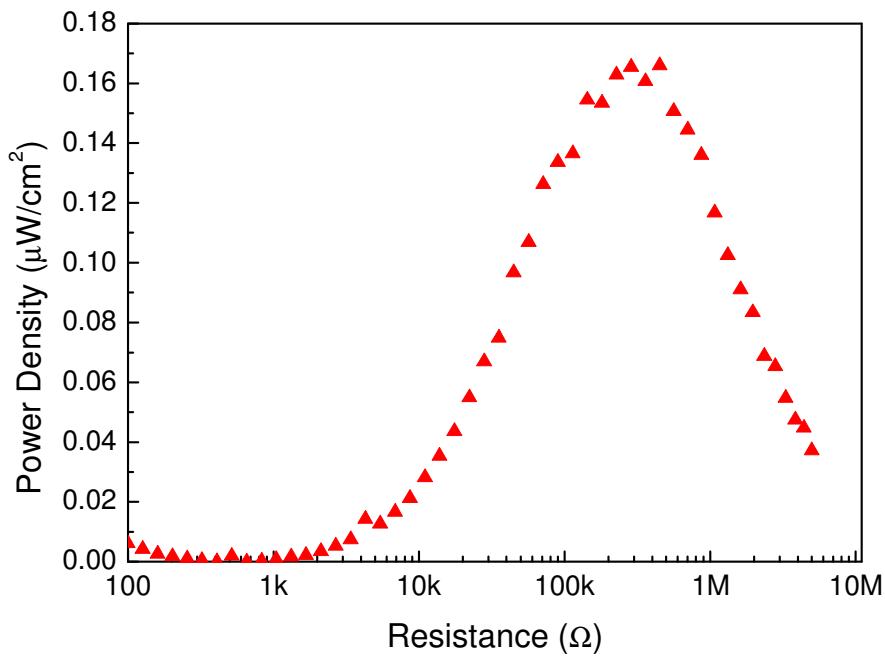
PEDOT:PSS



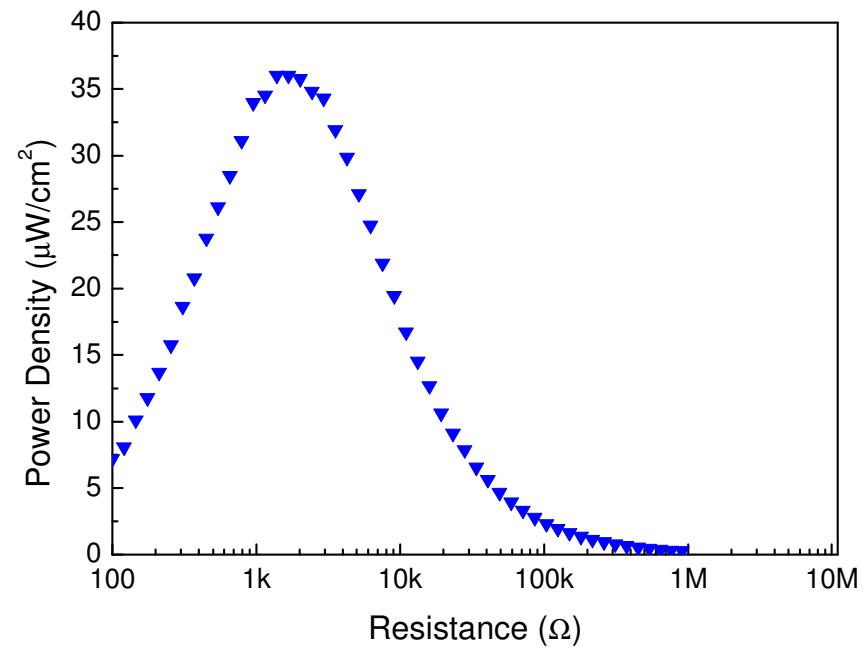
- Peak open-circuit voltage highest for PMMA device

Controlled bending - Load matching

PMMA



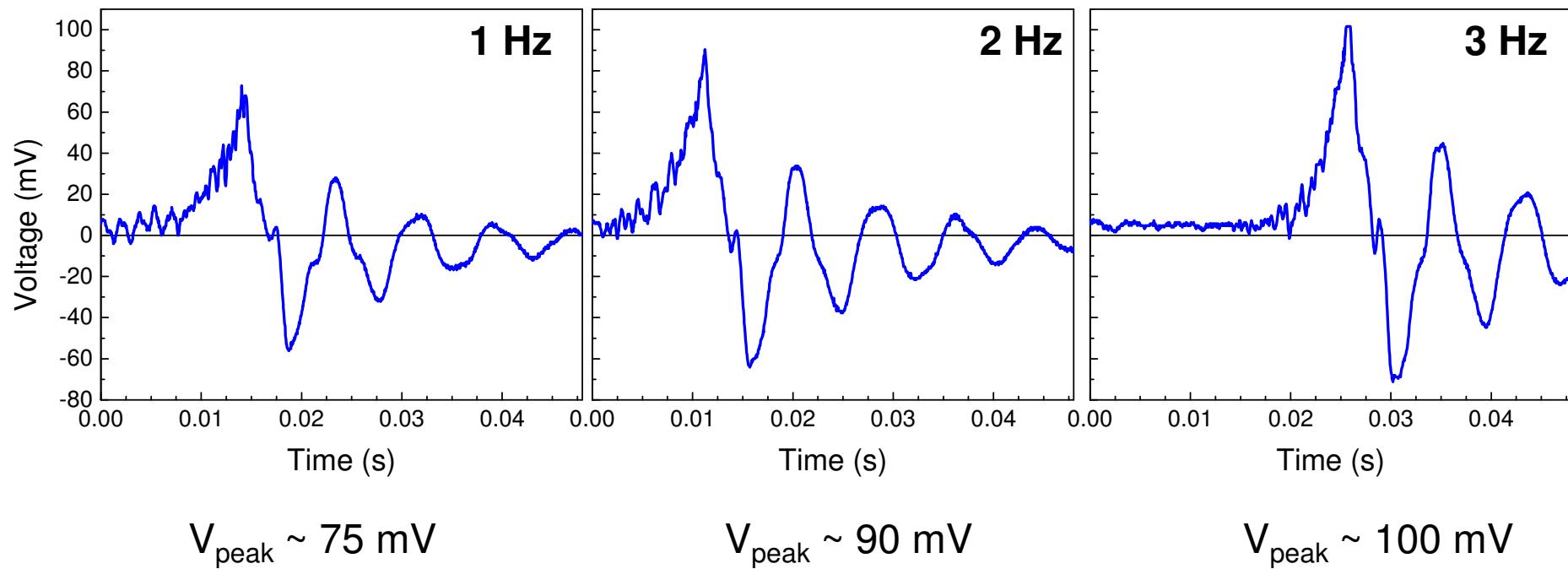
PEDOT:PSS



	ZnO/PMMA	ZnO/PEDOT:PSS
V_{oc} (mV)	252	90
Load R (k Ω)	286	1.68
Area power density (μWcm^{-2})	0.165	36
Volume power density (m Wcm^{-3})	0.30	144

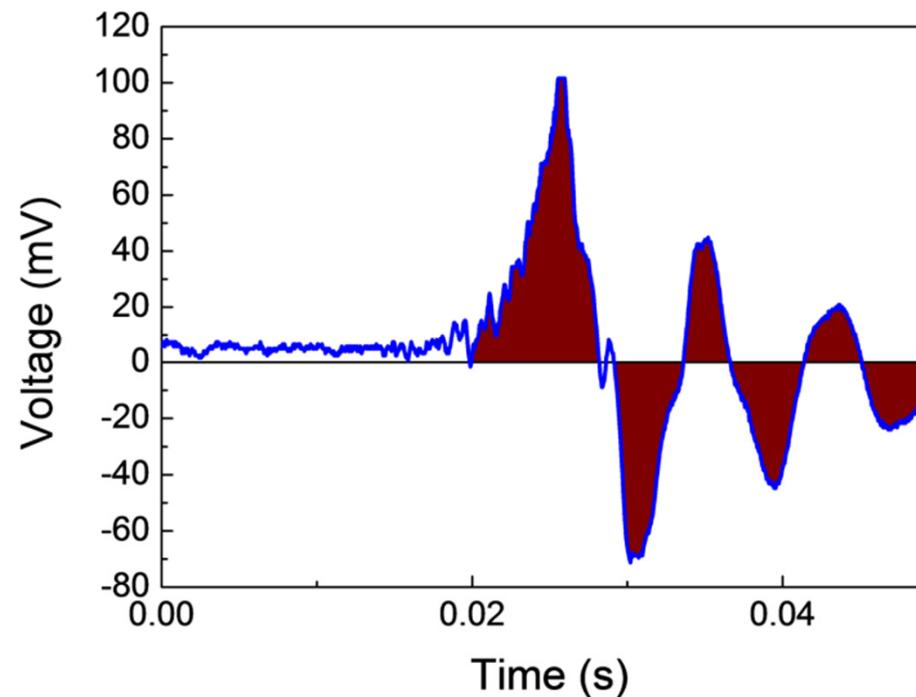
- Power from $V_{oc} \times J_{sc}$ overestimates by 4x

Controlled bending - Rate dependence



- Peak open-circuit voltage increases with bending rate (1 Hz leads to measured peak velocity of 0.8 m/s)

Controlled bending - Rate dependence



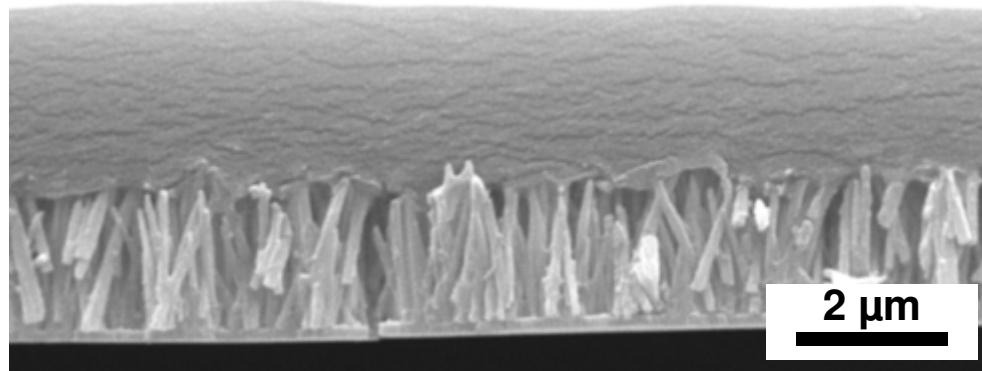
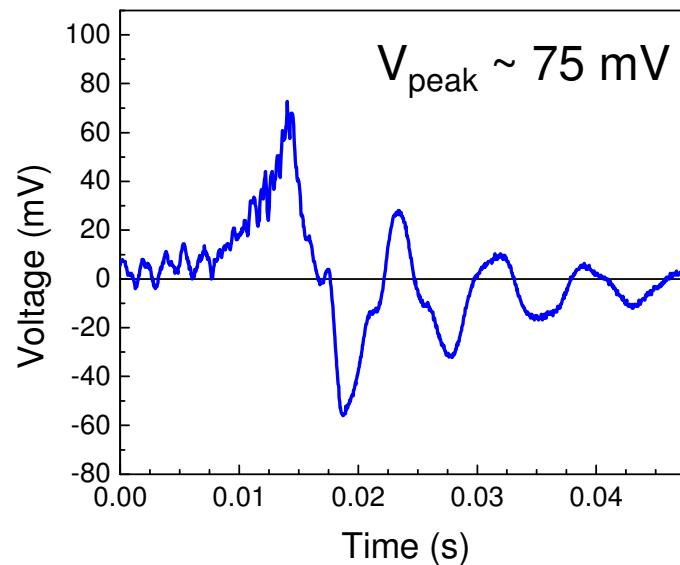
- Faster strain → higher peak voltage but with shorter duration.
- Total energy given by integrating over time:

$$E = \int_{t_1}^{t_2} \frac{V(t)^2}{R_{load}} dt$$

	ZnO/PMMA	ZnO/PEDOT:PSS
V_{oc} (mV)	252	90
Load R (kΩ)	286	1.68
Area power density (μWcm^{-2})	0.165	36
Volume power density (mWcm^{-3})	0.30	144
Energy output ($\text{nJcm}^{-2}/\text{cycle}$)	0.17	38.6

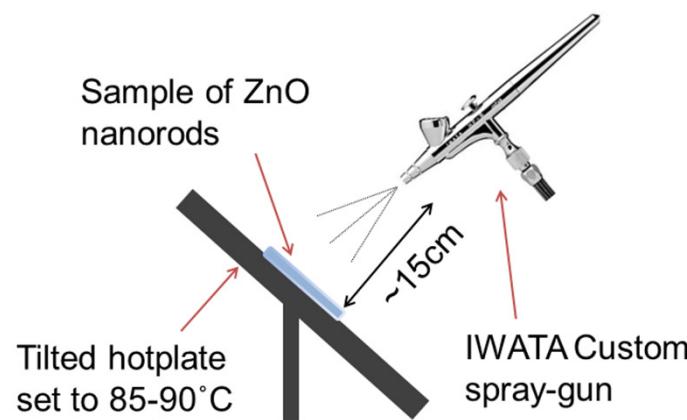
Device output

- Device output is still quite low
- Peak voltage is too low to be useful
- Need other ways to improve devices
- Is screening still an issue?
- What about the ZnO surface?



Surface passivation

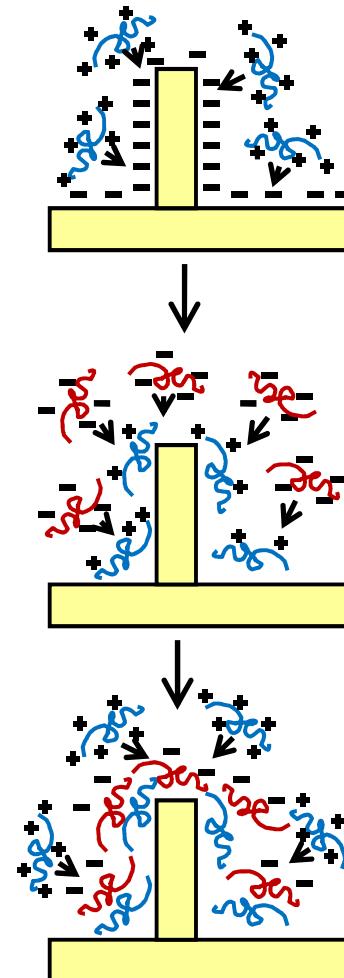
CuSCN spray deposition



- 0.15 M CuSCN solution in propyl sulphide spray-coated onto nanorods at ~80 °C
- 10 or 20 layers coated (5 or 10 ml)

Hatch, S., et al. (2013). *Thin Solid Films* 531: 404-407
DOI: 10.1016/j.tsf.2012.12.114

Layer-by-layer polyelectrolytes

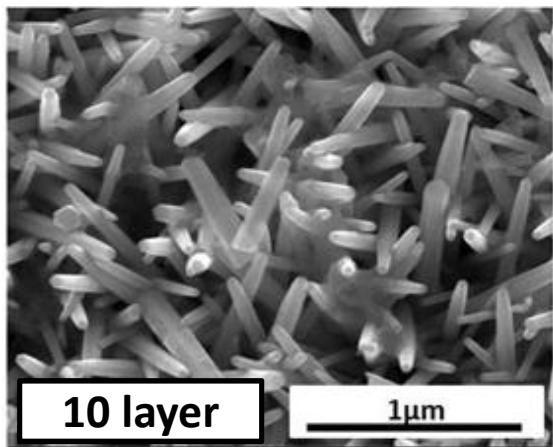


- Dipped into 10 wt%, aqueous solution of PDADMAC and rinsed with DI water
- Dipped into 10 wt% aqueous solution of PSS → 1 bilayer
- Repeated to form 2 or 4 bi-layers of polyelectrolytes

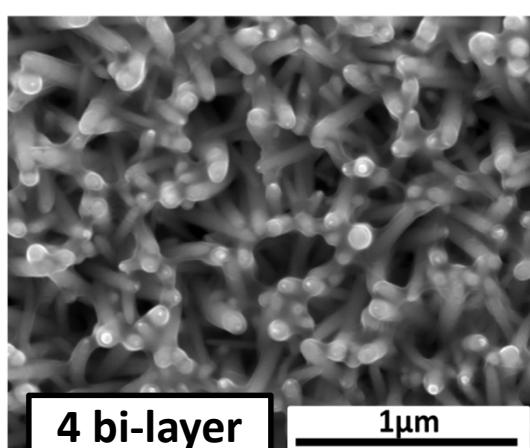
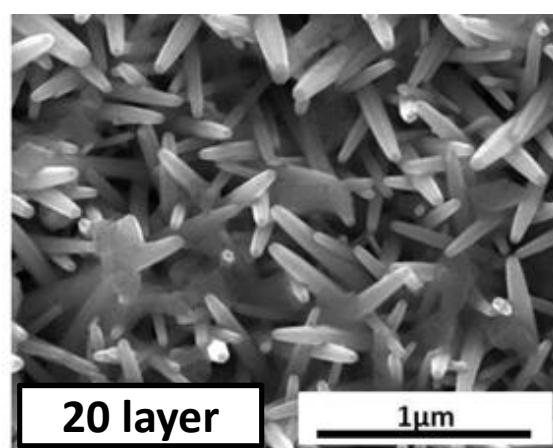
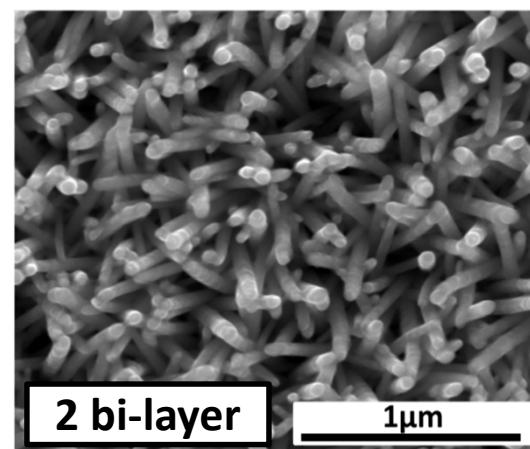
PDADMAC =
Poly(diallyldimethylammonium) chloride
PSS = Polystyrene sulfonate

ZnO nanorods: surface passivation

CuSCN spray deposition

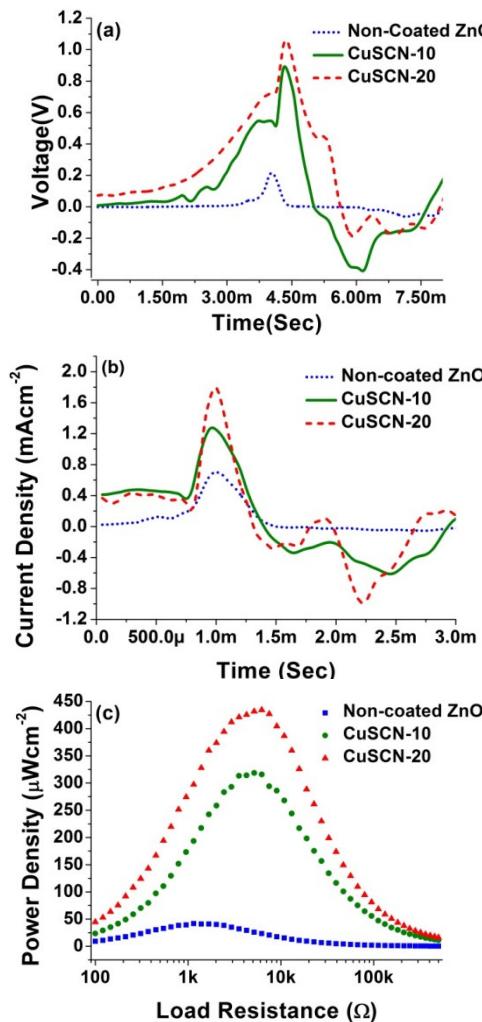


Layer-by-layer polyelectrolytes

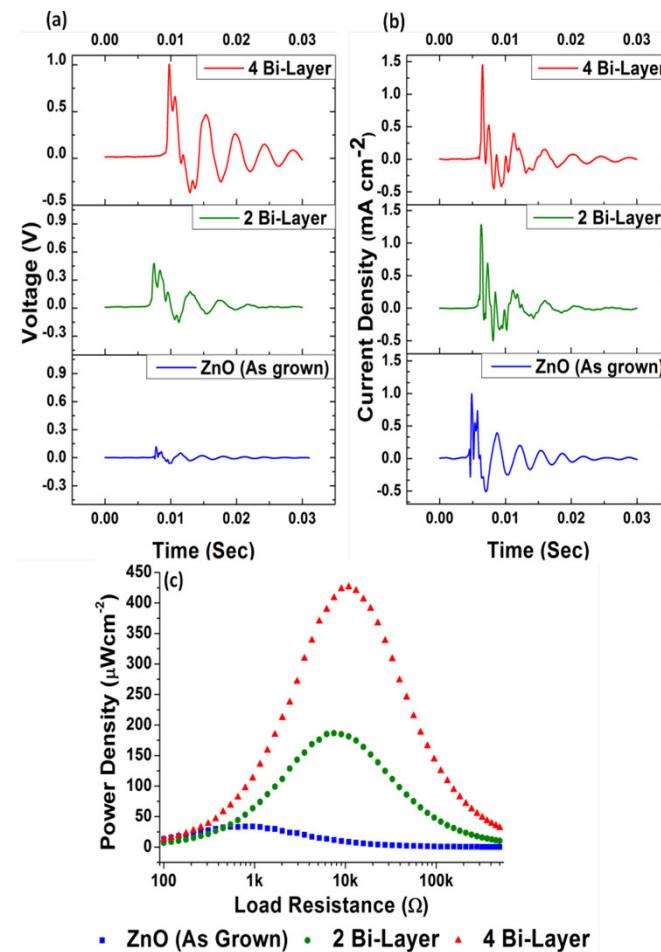


Power output

CuSCN

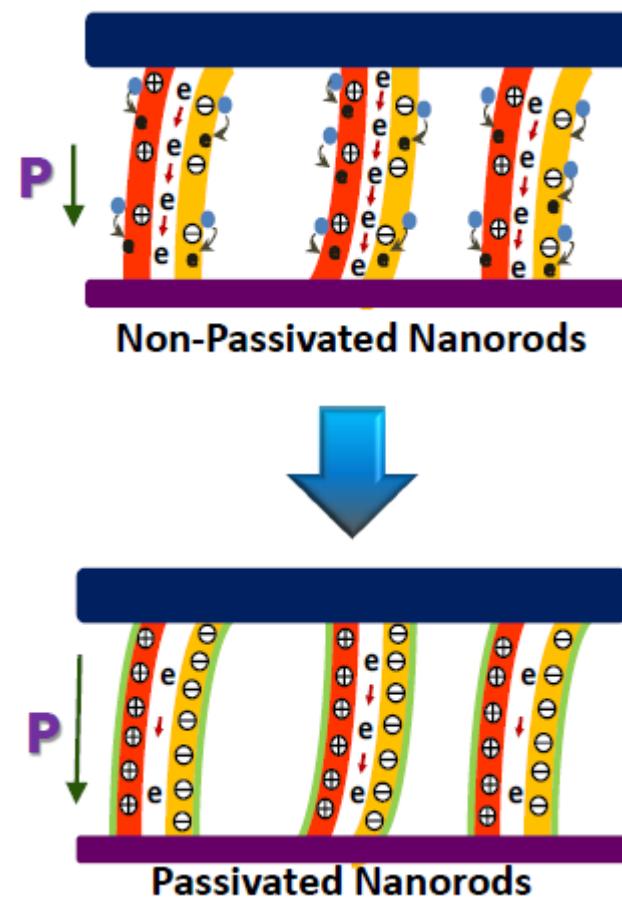


Polyelectrolytes



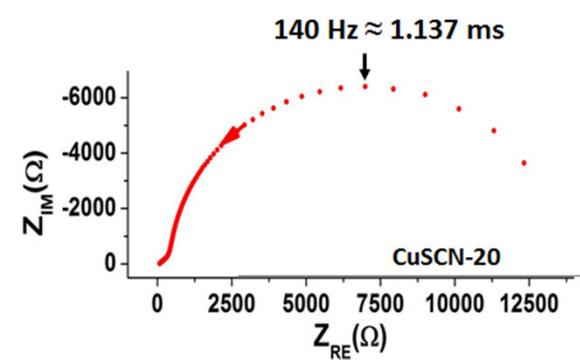
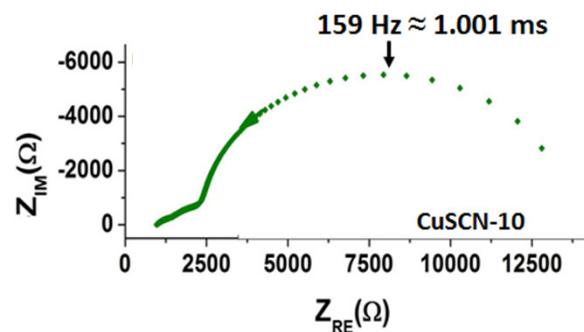
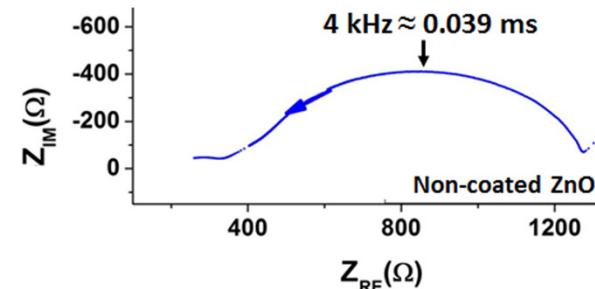
Mechanism

- Free carriers in ZnO screen polarisation internally by redistributing in response to the polarisation
- Passivation of surface reduces carrier concentration, reducing the internal screening

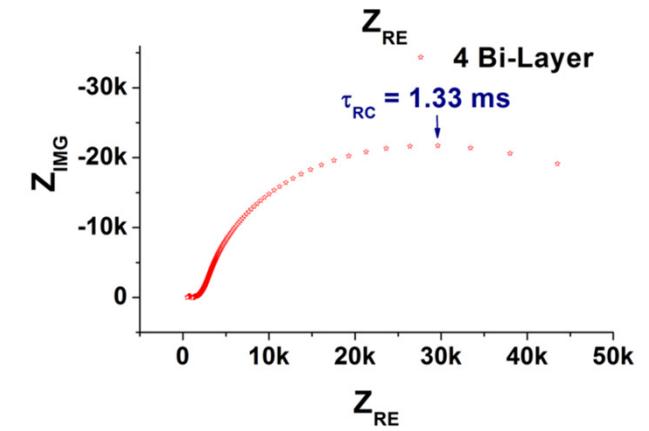
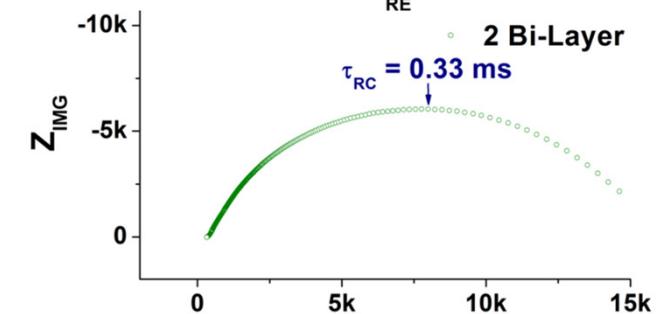
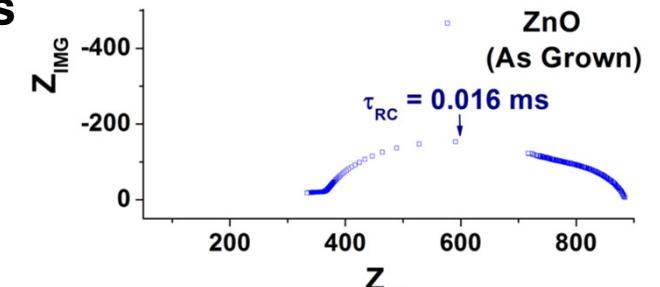


Electrical Impedance

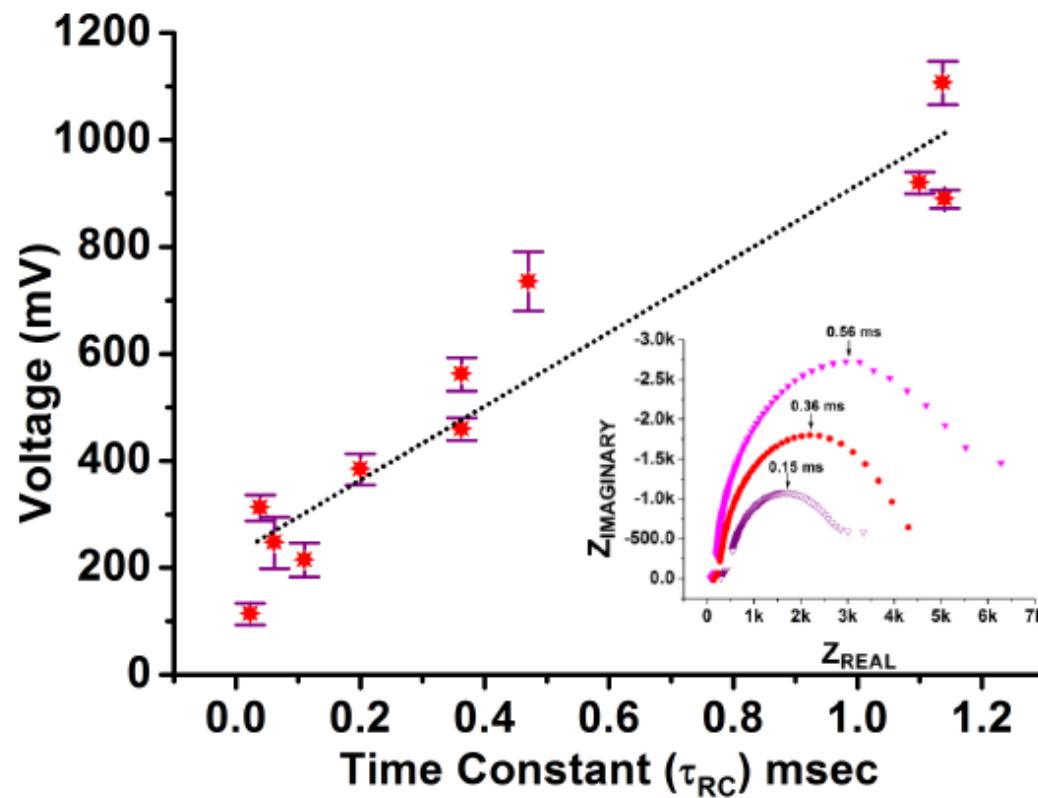
CuSCN



Polyelectrolytes



Electrical Impedance



- Time constant of system shows good correlation with peak voltage

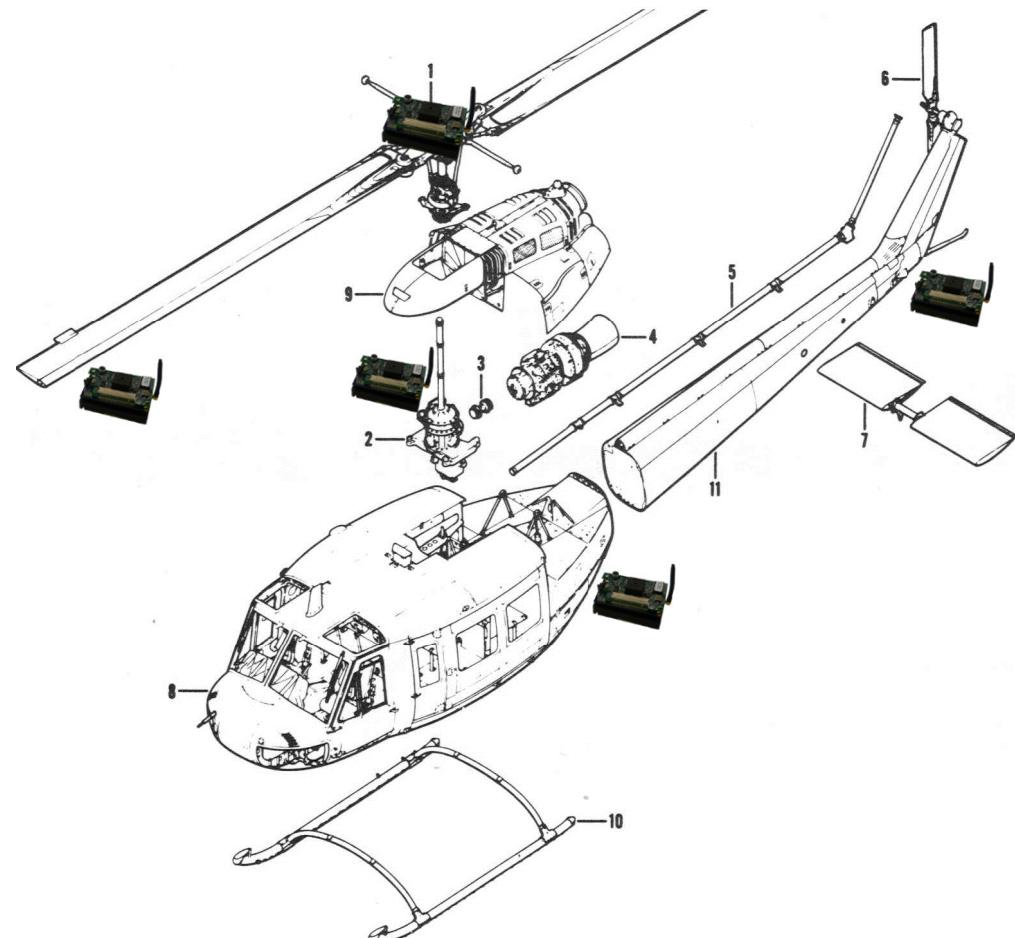
Wireless sensor nodes



- HUMS key to ensuring helicopter safety
- Components distributed through aircraft
- Vibration provides key indicator of component health
- Also provides excellent source of energy!

Wireless sensor nodes

- IVHM – ‘integrated vehicle health management’ - sensors distributed through aircraft
- Wiring in difficult and expensive
- Wireless nodes easy to install
- Ideally ‘fit and forget’
- Batteries require replacement
- Energy harvesting desirable



Summary

- ZnO nanorods produced by chemical methods on flexible, polymer substrates
- P-n junctions made with polymer p-type material to reduce rate of screening of polarisation
- Compared to ZnO/insulator structure, p-n junction delivers 200x more power on load despite 3x lower V_{oc}
- Nanorod surface passivated using either inorganic CuSCN, or a polymer layer, increasing power output due to reduced screening
- Devices investigated for helicopter sensor nodes
- Power output must be increased to give good duty cycle
- Recent investigations to vary seed layer, and top contact

Thank You

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Petr Novák

SPECIFIC, Swansea University, UK

Simone Meroni, Peter Greenwood, Joel Troughton,
Trystan Watson,

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Further information

Screening: J. Briscoe *et al.* (2012) *Adv. Energy Mater.* **2**, 1261–1268. doi: 10.1002/aenm.201200205

Measurement: J. Briscoe *et al.* (2013) *Energy Environ. Sci.* **6**: 3035–3045. doi: 10.1039/C3EE41889H

CuSCN passivation: N. Jalali *et al.* (2014) *J Mater Chem A* **2**:10945. doi: 10.1039/c4ta01714e

PDDA/PSS : N. Jalali *et al.* (2015) *J Sol-Gel Sci Technol* **73**:544–549. doi: 10.1007/s10971-014-3512-4

Efficiency measurements: J. Briscoe *et al.* (2012) *Appl. Phys. Lett.* **101**, 093902. doi: 10.1063/1.4749279

Review paper: J. Briscoe and S. Dunn (2015) *Nano Energy* **14**: 15–29 doi: 10.1016/j.nanoen.2014.11.059

